



PHOTONICS RESEARCH GROUP

Navolchi Update November 2013

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Physics and Chemistry of Nanostructures Group



http://www.nano.UGent.be

Overview of activities

- HgTe quantum dots
 - Low-threshold gain confirmed on number of samples
 - Extensive discussion on interpretation with theory group (C. Delerue, IEMN, Lille, France)
 - Opto-electronic properties calculated
 - Requirements for low-threshold gain defined
 - Quantification of effects not possible using their theoretical framwork (tight-binding calculations)
- Attempt to patent results stopped since prior art was found (generic QD lasing patent Klimov et al.)



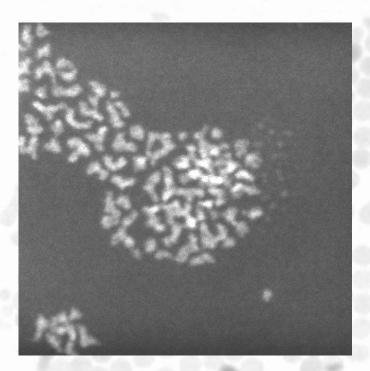
HgTe Quantum Dots

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- Synthesis tuning further explored (access to 1000-2500 nm wavelength range)
- Sample sent to UVE



HgTe Quantum Dots

Big issue – nanocrystals appear clustered in TEM

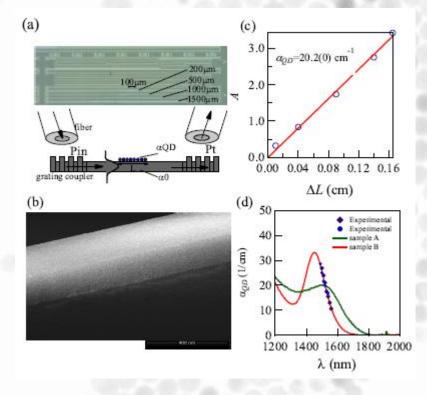


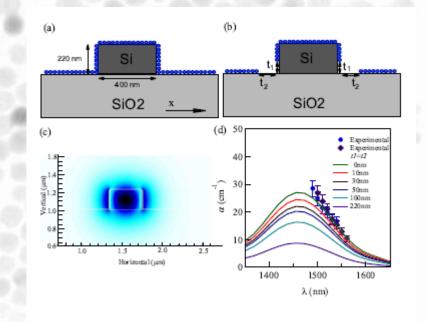
- Effect of drying on TEM grid
- Already like this in solution?
- Further measurements planned to sort this out + adaptations to the synthesis to prevent it



QD coated waveguides

 Theory on waveguide absorption coefficient extended to strip waveguides









Understanding clustering in HgTe QD synthesis

